The RF Line Wideband Linear Amplifier

... designed for amplifier applications in 50 to 100 ohm systems requiring wide bandwidth, low noise and low distortion. This hybrid provides excellent gain stability with temperature and linear amplification as a result of the push–pull circuit design.

Specified Characteristics at V_{CC} = 28 V, T_C = 25°C:
 Frequency Range — 1 to 200 MHz
 Output Power — 1580 mW Typ @ 1 dB Compression, f = 200 MHz
 Power Gain — 35.5 dB Typ @ f = 100 MHz
 PEP — 900 mW Typ @ -32 dB IMD
 Noise Figure — 5 dB Typ @ f = 200 MHz
 ITO — 47 dBm @ f = 200 MHz

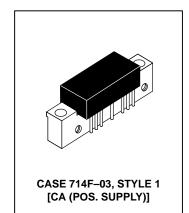
- · All Gold Metallization for Improved Reliability
- Unconditional Stability Under All Load Conditions

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
DC Supply Voltage	Vcc	30	Vdc
RF Power Input	Pin	+5	dBm
Operating Case Temperature Range	TC	-20 to +90	°C
Storage Temperature Range	T _{stg}	-40 to +100	°C

CA2832C

35.5 dB 1-200 MHz 1.6 WATT WIDEBAND LINEAR AMPLIFIER



ELECTRICAL CHARACTERISTICS (T_C = 25°C, V_{CC} = 28 V, 50 Ω system unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Frequency Range	BW	1	_	200	MHz
Gain Flatness (f = 1-200 MHz)	_	_	±0.5	±1	dB
Power Gain (f = 100 MHz)	PG	34	35.5	37	dB
Noise Figure, Broadband (f = 200 MHz)	NF	_	5	6	dB
Power Output — 1 dB Compression (f = 1-200 MHz)	P _{o 1dB}	1260	1580	_	mW
Power Output — 1 dB Compression (f = 150 MHz)	P _{o 1dB}	_	2000	_	mW
Third Order Intercept (See Figure 10, f ₁ = 200 MHz)	ITO	45	47	_	dBm
Input/Output VSWR (f = 1-200 MHz)	VSWR	_	1.5:1	2:1	_
Second Harmonic Distortion (P ₀ = 100 mW, f _{2H} = 150 MHz)	d _{SO}	_	-70	-60	dB
Peak Envelope Power (Two Tone Distortion Test — See Figure 10) (f = 1-200 MHz @ -32 dB IMD)	PEP	_	900	_	mW
Supply Current	Icc	400	435	470	mA

TYPICAL CHARACTERISTICS

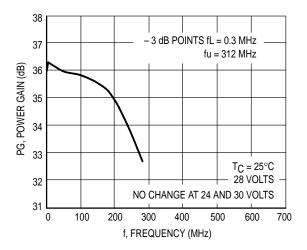


Figure 1. Power Gain versus Voltage

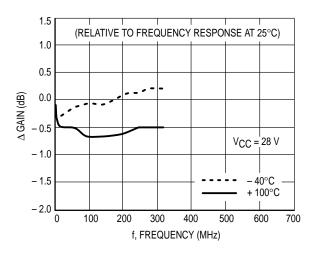


Figure 2. Relative Power Gain versus Temperature

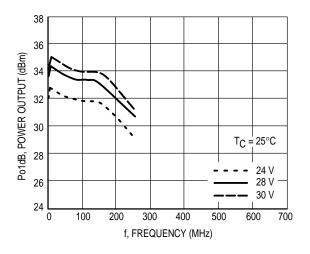


Figure 3. 1 dB Compression versus Voltage

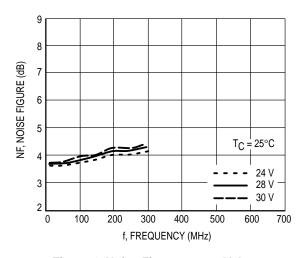


Figure 4. Noise Figure versus Voltage

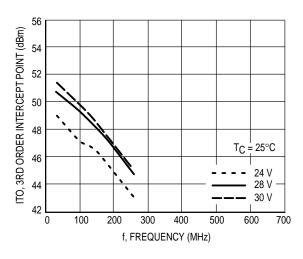


Figure 5. Third Order Intercept versus Voltage

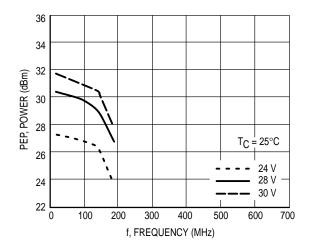
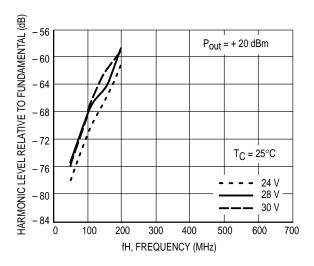


Figure 6. Peak Envelope Power versus Voltage



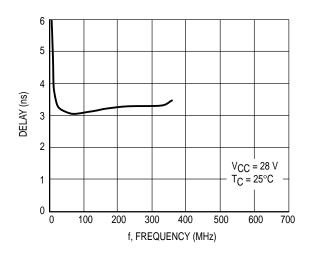


Figure 7. Second Harmonic Distortion versus Voltage

Figure 8. Group Delay versus Frequency

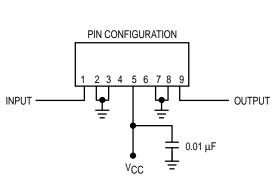
Biased at 28 Volts

 $T_C = 25^{\circ}C$ $Z_O = 50\Omega$

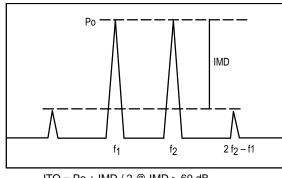
Frequency (MHz)	S11		S21		S12		S22	
	Mag	Ang	Mag	Ang	Mag	Ang	Mag	Ang
1	-16.7	64	36.0	23.3	-42	-5.2	-12.9	73
10	-21.5	21	36.2	-8.4	-47	-1.4	-21.9	28
50	-18.5	6.8	35.9	-56	-44	2.8	-17.9	-10
100	-16.9	-1.8	35.7	-103	-46	-68	-15.7	-48
200	-12.9	-18	34.7	145	-49	-98	-14.9	115

Magnitude in dB, Phase Angle in degrees.

Table 1. S-Parameters



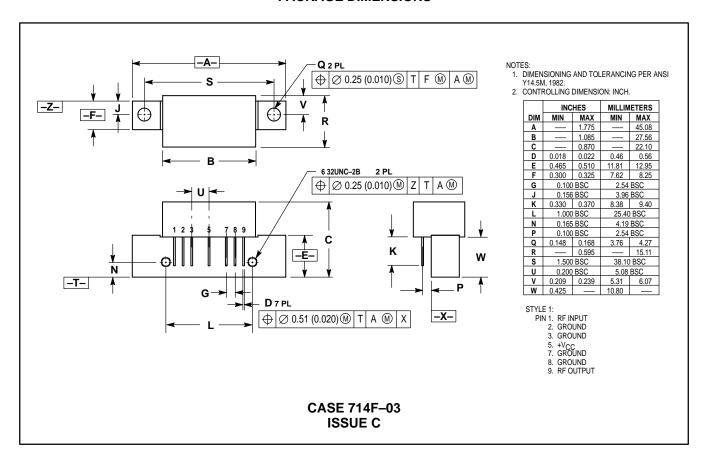




ITO = Po + IMD / 2 @ IMD > 60 dB $PEP = 4 \times Po @ IMD = -32 dB$

Figure 10. Intermodulation Test

PACKAGE DIMENSIONS



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